



Effective emittance reduction using variable field dipoles in electron storage rings Yannis PAPAPHILIPPOU CERN

United States Particle Accelerator School, University of California - Santa-Cruz, Santa Rosa, CA 14th – 18th January 2008



Lattice upgrade options



- Vertical emittance $\epsilon_y \approx 0.01 \epsilon_x'$ ie to coupling
- Horizontal emittance depends on the energy, the bending angle and the damping partition number

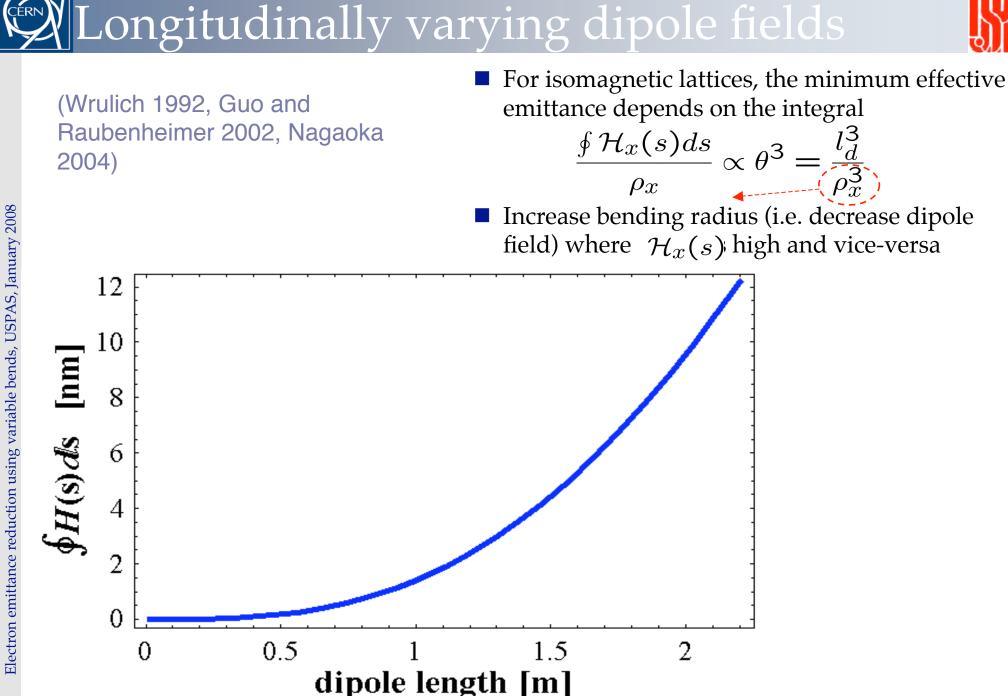
Vary field along bending magnet to increase radiation damping, i.e. Double Variable Bend structure

 $\epsilon_x \propto$

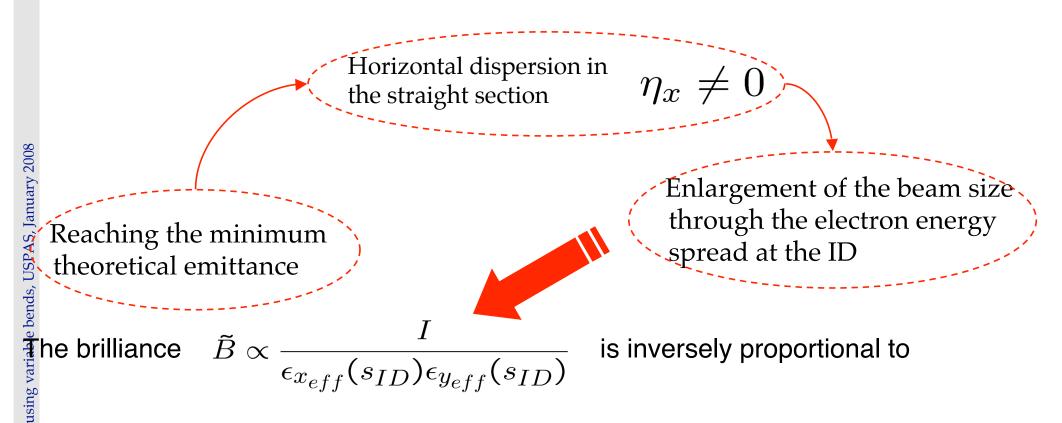
Increase number of dipoles, e.g. from **Double Bend** to **Triple Bend** structure. Difficult due to space constraints

Decrease the energy is not an attractive option for the ESRF (ID's are optimized for 6GeV)

Increase the damping partition number is mostly used for matching and not for emittance minimisation.







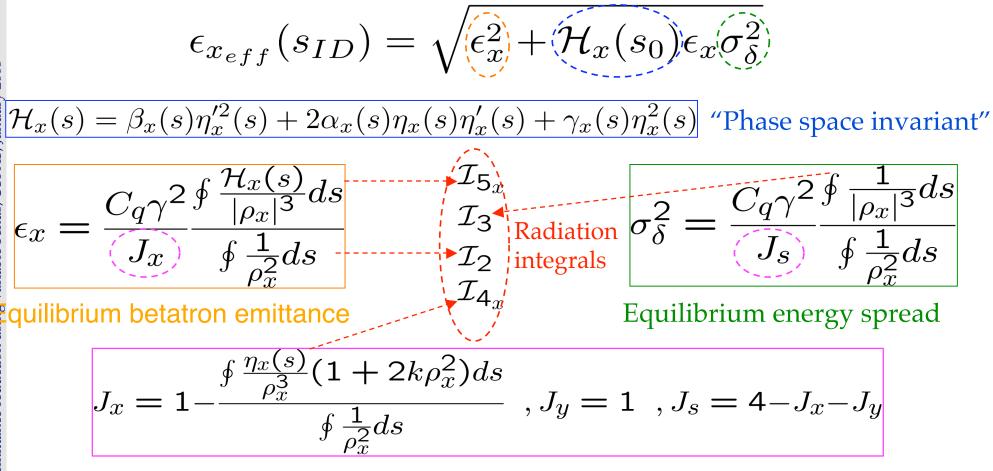
the effective emittance $\epsilon_{x;eff}(s)^2 \equiv \langle x(s)^2 \rangle \langle x'(s)^2 \rangle - \langle x(s)x'(s) \rangle^2$. After replacing the expressions for position and angles and consider that the alpha function and dispersion derivative are zero on the ID

$$\epsilon_{x_{eff}}(s_{ID}) = \sqrt{\epsilon_x^2 + \mathcal{H}_x(s_0)\epsilon_x\sigma_\delta^2}$$

Electron emit







Damping partition numbers



ble bends, USPAS, January 2008

Electron emittance reduction using va



Consider the transport matrix of a generalized dipole magnet with varying bending radius, in thin lens approximation and ignoring edge focusing

$$\mathcal{M}_{bend} = \begin{pmatrix} 1 & s & \theta(s) \\ 0 & 1 & \theta(s) \\ 0 & 0 & 1 \end{pmatrix} (\theta(s) = \int_0^s \frac{ds'}{\rho(s')} \ , \ \ \widetilde{\theta(s)} = \int_0^s \theta(s') ds')$$

At its entrance (from the ID side) the initial optics functions are β_0 , α_0 , γ_0 , η_0 , η'_0

and their evolution along the magnet is given by

$$\beta(s) = \beta_0 - 2s\alpha_0 + s^2\gamma_0$$

$$\alpha(s) = \alpha_0 - s\gamma_0$$

$$\gamma(s) = \gamma_0$$

$$\eta(s) = \eta_0 + s\eta'_0 + \tilde{\theta(s)}$$

$$\eta(s) = \eta'_0 + \theta(s)$$

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The transverse emittance is $e^{-1} = \frac{1}{J_x \oint \frac{1}{p_x^2} ds} \left[\beta_0 (A_3 + 2A2\eta_0' + A1\eta_0'^2) + \alpha_0 (2A5 + 2A4\eta_0' + \eta_0 (2A2 + 2A1\eta_0')) + \gamma 0 (A6 + 2A4\eta_0 + A1\eta_0^2) \right]$ wit $A1 = \oint \frac{1}{|\rho^3|} ds$, $A2 = \oint \frac{\theta(s)}{|\rho^3|} ds$, $A3 = -\oint \frac{\theta(s)^2}{|\rho^3|} ds$ $A4 = \oint \frac{\theta(s) - s\theta(s)}{|\rho^3|} ds$, $A5 = \oint \frac{(\theta(s) - s\theta(s))^2}{|\rho^3|} ds$, $A6 = -\oint \frac{\theta(s)(\theta(s) - s\theta(s))}{|\rho^3|} ds$ By setting $J_s = 2J_x$ we get an expression of the effective emittance at the ID, depending on the initial optics functions $e^2_{x_{eff}} = \frac{C}{2} \left[\gamma_0 (A6 + 2A4\eta_0 + A1\eta_0^2) + 2\alpha_0 (A5 + A2\eta_0 + A4\eta_0' + A1\eta_0\eta_0') + \beta_0 (A3 + 2A2\eta_0' + A1\eta_0'^2) \right]$ $\left[\gamma_0 (2A6 + 4A4\eta_0 + 3A1\eta_0^2) + 2\alpha_0 (2A5 + 2A2\eta_0 + 2A4\eta_0' + 3A1\eta_0\eta_0') + \beta_0 (2A3 + 4A2\eta_0' + 3A1\eta_0'^2) \right]$

$${}_{ff} = \frac{C}{2} \left[\gamma_0 (A6 + 2A4\eta_0 + A1\eta_0^2) + 2\alpha_0 (A5 + A2\eta_0 + A4\eta_0' + A1\eta_0\eta_0') + \beta_0 (A3 + 2A2\eta_0' + A1\eta_0'^2) \right] \\ \left[\gamma_0 (2A6 + 4A4\eta_0 + 3A1\eta_0^2) + 2\alpha_0 (2A5 + 2A2\eta_0 + 2A4\eta_0' + 3A1\eta_0\eta_0') + \beta_0 (2A3 + 4A2\eta_0' + 3A1\eta_0'^2) \right]$$





The conditions for minimum effective emittance are

$$\frac{\partial \epsilon_{x_{eff}}^2}{\partial \eta_0} = 0 \quad , \frac{\partial \epsilon_{x_{eff}}^2}{\partial \eta_0'} = 0 \quad , \frac{\partial \epsilon_{x_{eff}}^2}{\partial \beta_0} = 0 \quad , \frac{\partial \epsilon_{x_{eff}}^2}{\partial \alpha_0} = 0$$

After some lengthy manipulations and exploiting certain symmetries of the equations, we obtain the following relations

$$\eta_0 = \frac{A4}{A2}\eta'_0 \quad , \gamma_0 = \frac{A2(A3 + A2\eta'_0)\beta_0}{2A2A6 + A4^2\eta'_0} \quad , \alpha_0 = -\frac{A2(A5 + A4\eta'_0)\beta_0}{2A2A6 + A4^2\eta'_0}$$

Finally, one has to solve the following equation for the dispersion

$$\frac{3\eta_0'^3 + 10T1\eta_0'^2 + T1^2(6 - 5T2)\eta_0' - 4T1^3T2 = 0}{T1 = \frac{A2}{A1}}$$
$$T2 = \frac{A1(A5^2 - A3A6)}{A3A4^2 + A2(-2A4A5 + A2A6)}$$

ptics functions and minimum effective emittance for arbitrary dipole fields



Keeping the real solution of the 3rd order polynomial equation, and replacing in the previous conditions, we obtain the optics functions for minimum effective emittance

$$\begin{split} \beta_0 &= \frac{9A1A6T + A4^2(46 + (-10 + T)T + 45T2)}{3\sqrt{A1A3(A4^2 + A2(-2A4A5 + A2A6))T(46 + T(-10 + T - 9T2) + 45T2}} \ ,\\ \alpha_0 &= -\frac{A1(9A5T + A4T1(46 + (-10 + T)T + 45T2)}{3\sqrt{A1(A4^2 + A2(-2A4A5 + A2A6))T(46 + T(-10 + T - 9T2) + 45T2}} \ ,\\ \eta_0 &= \frac{A4(-10 + T + \frac{46 + 45T2}{T})}{9A1} \ ,\\ \eta'_0 &= \frac{T1(-10 + T + \frac{46 + 45T2}{T})}{9} \ ,\\ \text{with} \qquad T &= \left(-190 - 189T2 + 9\sqrt{-3(1 + T2)(2 + 3T2)(126 + 125T2)}\right)^{\frac{1}{3}} \ .\\ \text{By replacing, we get an analytic expression for the minimum effective emittance for any dipole field profile} \\ &= \frac{C}{9}\sqrt{\frac{S2(T^4 - 2T^3 - 6T^2(3T2 - 2) - 2T(45T2 + 46) + (45T2 + 46)^2)(T^4 + 7T^3 - 6T^2(12T2 + 13) + 7T(45T2 + 46) + (45T2 + 46)^2)}{6A1T^3(46 + T(-10 + T - 9T2) + 45T2)}} \end{split}$$





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In the case of constant field we obtain the relation of Tanaka and Ando (1996)

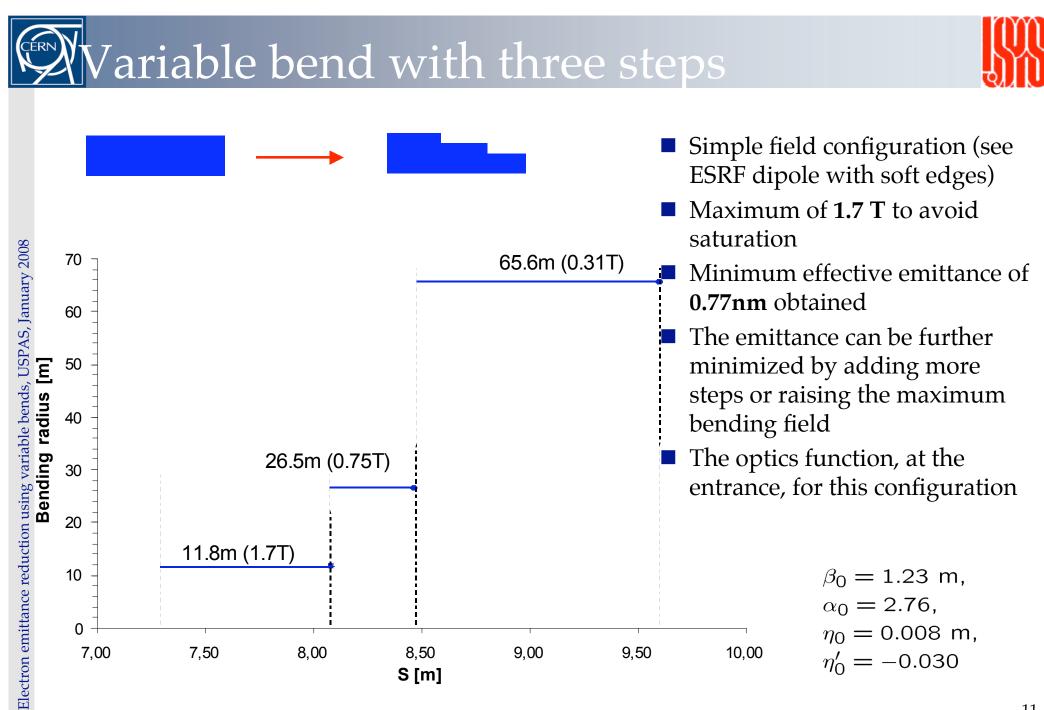
which is a factor of **1.55** higher than the minimum betatron emittance

- For an ESRF Double Bend lattice (64 dipoles, 6GeV), the minimum effective emittance is 1.69nm
- Setting $A = (2A_2A_4 A_1A_5)A_5 A_2^2A_6 + A_3(A_1A_6 A_4^2)$, the minimum betatron emittance is obtained for the optics function $\epsilon_{x;min} = \frac{2C\sqrt{A_1A}}{A_1}$ conditions $\eta_0 = -\frac{A_4}{A_1}$, $\beta_0 = \frac{-A_4^2 + A_1A_6}{\sqrt{A_1A}}$, $\eta'_0 = -\frac{A_2}{A_1}$, $\alpha_0 = \frac{A_2A_4 - A_1A_5}{\sqrt{A_1A}}$.
 Imposing achromatic conditions $\eta_0 = \eta'_0 = 0$
- the minimum betatron (=effective) emittance $\epsilon_{x;min} = 2C\sqrt{A_3A_6 A_5^2}$ is obtained for the optics function conditions

$$\beta_0 = \frac{A_6}{\sqrt{A_3 A_6 - A_5^2}} \quad , \alpha_0 = \frac{A_5}{\sqrt{A_3 A_6 - A_5^2}} \quad .$$

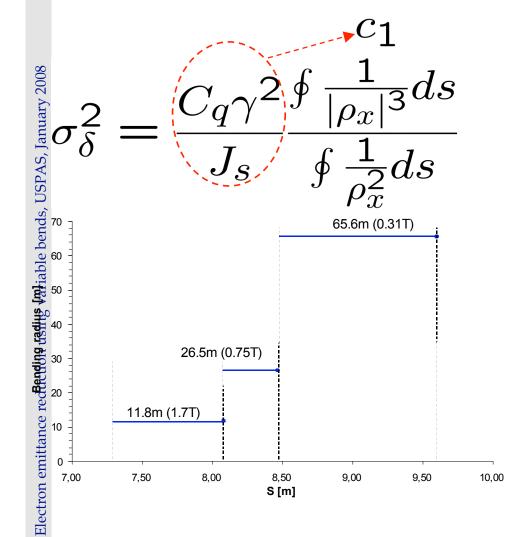
 $\epsilon_{x;eff_{min}} = 0.03339C_q \frac{\gamma^2 \theta^3}{J_r}$

 $\epsilon_{x_{min}} = \frac{1}{12\sqrt{15}} C_q \frac{\gamma^2 \theta^3}{J_r}$



Equilibrium energy spread in a DVB





For a uniform field dipole

$$\sigma_{\delta} = \sqrt{\frac{c_1}{\rho_x}} = \sqrt{c_1 \frac{\theta}{l}}$$

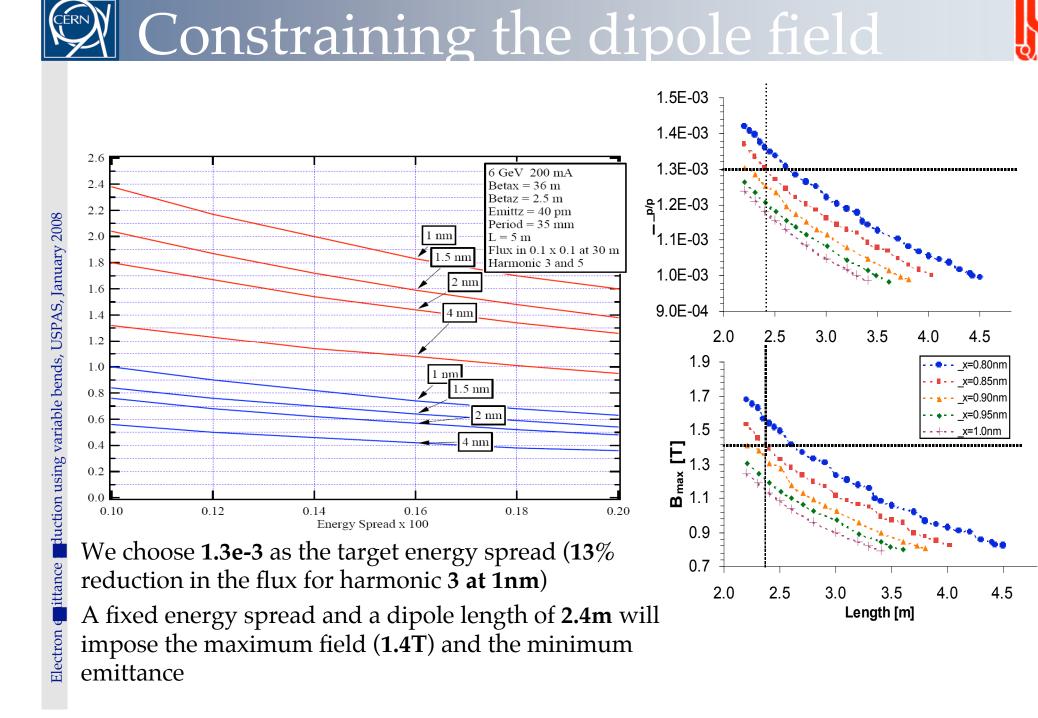
For the Variable 3-step bend

$$\rho_1 \approx 2\rho , \ \rho_2 \approx \rho , \ \rho_3 \approx \rho/2$$

and $l_1 \approx l/3$, $l_2 \approx l/12$, $l_3 \approx l/2$ The energy spread is

$$\sigma_{\delta} \approx \frac{3}{2} \sqrt{\frac{11}{13}} \sigma_{\delta_{ESRF}} = 1.4610^{-3}$$

Taking the uniform field approximation this implies that for having the same energy dispersion $l_{tot} \approx \frac{99 l}{52} = 1.9l \approx 4.4m$ and the max. field should drop accordingly



Choosing the variable dipole Minimum emittance achieved of **0.85nm** Maximum field of 1.4T **Bending field** [1.5 0.5 0 1.5 Initial optics $\beta_0 = 1.49$ m, functions are $\alpha_0 = 2.6$, $\eta_0 = 0.011 \text{ m},$ $\eta_0' = -0.031$ $\beta_0 = 1.23 \text{ m},$ compared to $\alpha_0 = 2.76$, for the extreme $\eta_0 = 0.008 \text{ m},$

Length [m]

DVB (0.77nm)

3 and for the

actual SR

Note that

beta at the dipole exit is 19m

0

 $\eta_0' = -0.030$

 $\beta_0 = 1.79$ m,

 $\eta_0 = 0.073 \text{ m},$

 $\eta'_0 = -0.080$

 $\alpha_0 = 1.39$,

Phase advance for minimum effective emittance cell



- General rule: Provided that dispersion is not zero, there is a unique phase advance for a straight section with mirror symmetry in the center
- Given the initial (final) optics functions $\beta_0, \alpha_0, \eta_0, \eta'_0$ phase advance for such a line is $\tan(\mu) = \frac{2\eta_0(\beta_0\eta'_0 + \alpha_0\eta_0)}{(\beta_0\eta'_0 + (\alpha_0 - 1)\eta_0)(\beta_0\eta'_0 + (\alpha_0 + 1)\eta_0)}$
- Applying the result to an arbitrary double bend cell, we obtain $\mu_{cell} = \mu_{cell}(\beta_0, \alpha_0, \eta_0, \eta'_0, l_d, \theta, \tilde{\theta})$
 - a function depending **only** on the initial optics functions and the dipole !!!
- The horizontal phase advance for reaching the absolute minimum effective emittance at the ESRF storage ring is **293** (**205** actually) The horizontal phase advance for reaching the effective emittance minimum for the three step double variable bend lattice is 355



Emittance ratio for detuned optics functions

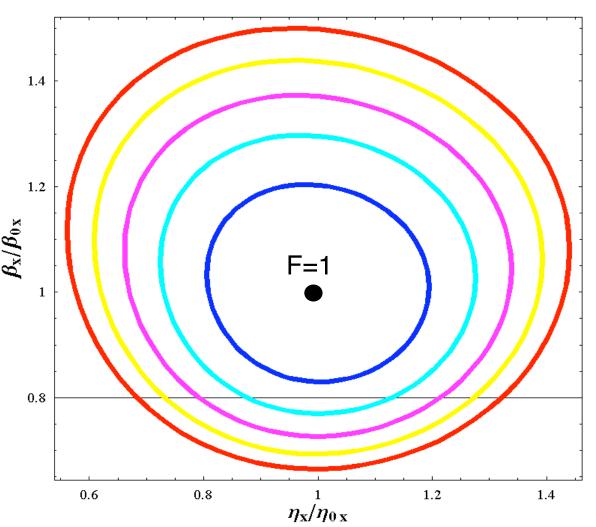


By detuning the initial beta and dispersion we obtain curves of equal effective emittance ratio

 $F = \frac{\epsilon_{x_{eff}}}{\epsilon_{x_{eff}}}$ Pose $\int \epsilon_{x_{eff}} 4$ parametric plot for all optics
functions

Note that by detuning the optics functions, the phase advance also changes (lower for higher F values)

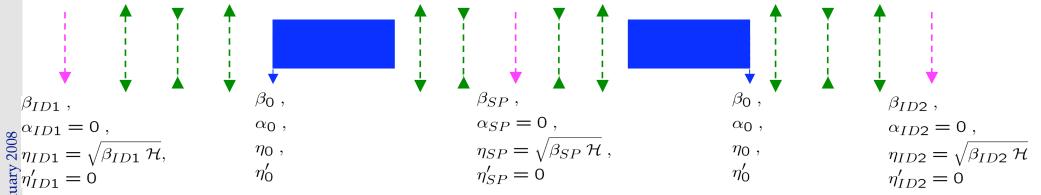
(Emma and Raubenheimer 2001, Streun 2001, Korostelev and Zimmermann 2003)





Constraints for general double bend cells





- Consider a general double bend with the ideal effective emittance (drifts are parameters)
- In the straight section between the ID and the dipole entrance, there are three constraints, thus at least three quadrupoles are needed
- In the "achromat", there are two constraints, thus at least two quadrupoles are needed (one and a half for a symmetric cell)
- Note that there is **no control** in the vertical plane

- The vertical phase advance is also fixed!!!!
- Expressions for the quadrupole gradients can be obtained, parameterized with the drift lengths, the initial optics functions and the beta on the IDs
- All the optics functions are thus uniquely determined for both planes and can be minimized (the gradients as well) by varying the drifts
- The chromaticities are also uniquely defined





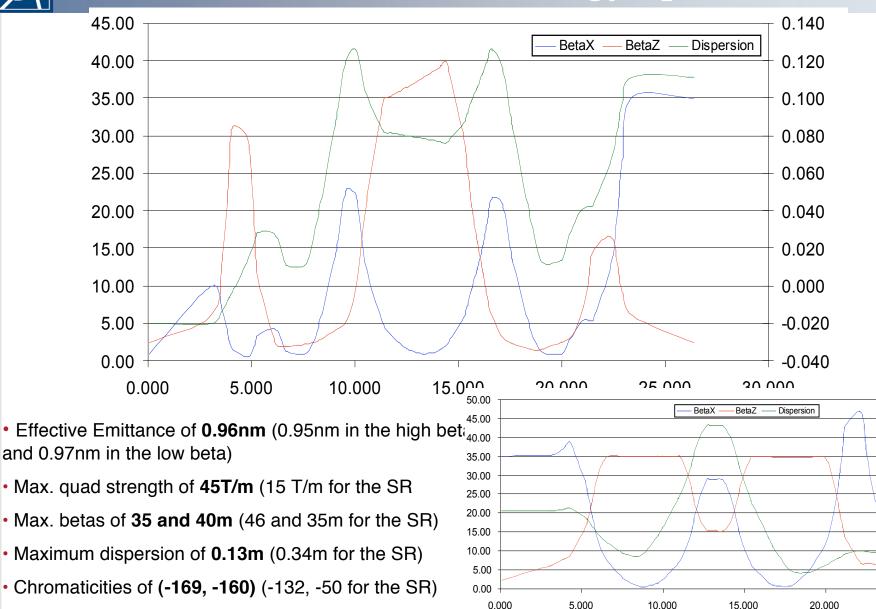
Constraints for the dipole

- \Box Energy of **6GeV**, **64** dipoles, i.e. total bending radius of $\pi/32$
- Dipole length of **2.3m**
- □ Maximum dipole field of **1.4T** (imposed by momentum spread of 1.3e-3)

Constraints for the drifts

- Cell length of **26.4m**
- □ ID drift of **3m** wertical beta of **2.5m** at the ID
- \Box Drift next to dipoles ρ **0.5m** (space for the absorber)
- \Box Drifts between quadrupoles ρ **0.5m** (space for sextupoles, correctors, BPM, etc.)
- Constraints for the quadrupoles
 - □ Maximum gradient of **45T/m** (reducing the bore diameter by a factor of 2)
- Constraints for the sextupoles
 - $\label{eq:maximum integrated sextupole strength of 35m^{-2} \quad \mbox{(Master thesis of T. Perron 2002)}$
- Constraints for the optics functions

Extreme DVB with low energy spread



Phase adv. of (357°,166°) (205°,81° for the SR)

19

30.000

25.000

0.40

0.35

0.30

0.25

0.20

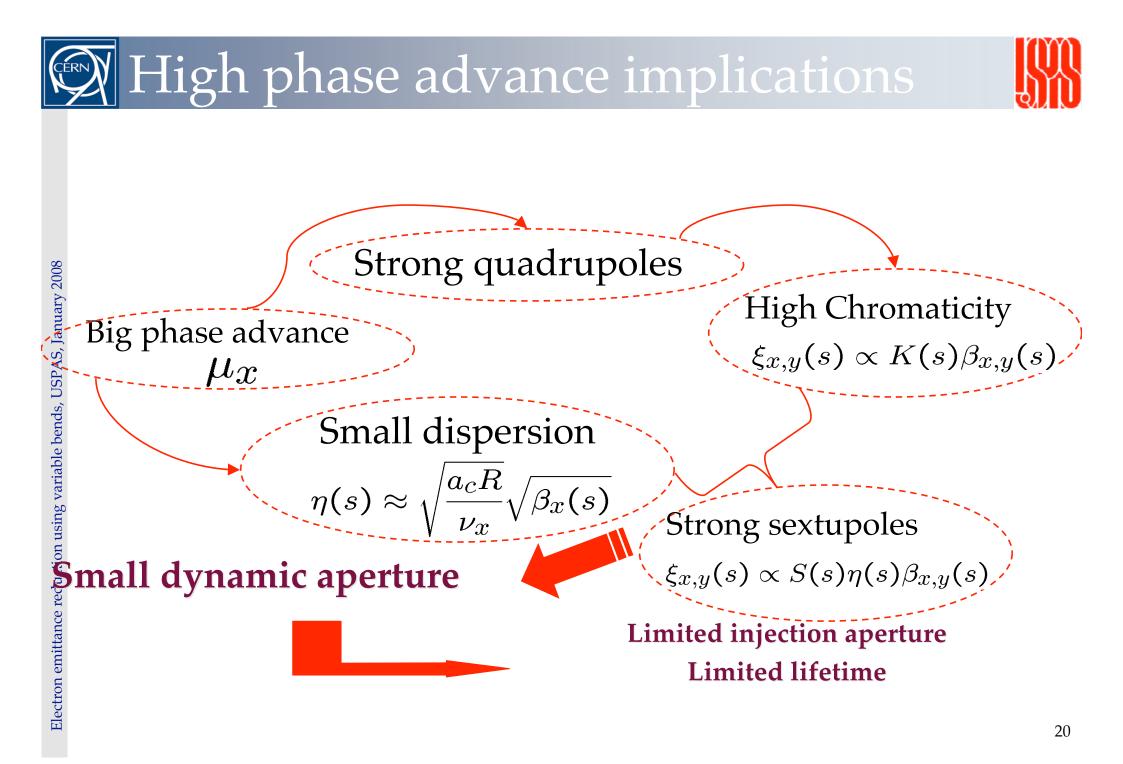
0.15

0.10

0.05

0.00

-0.05

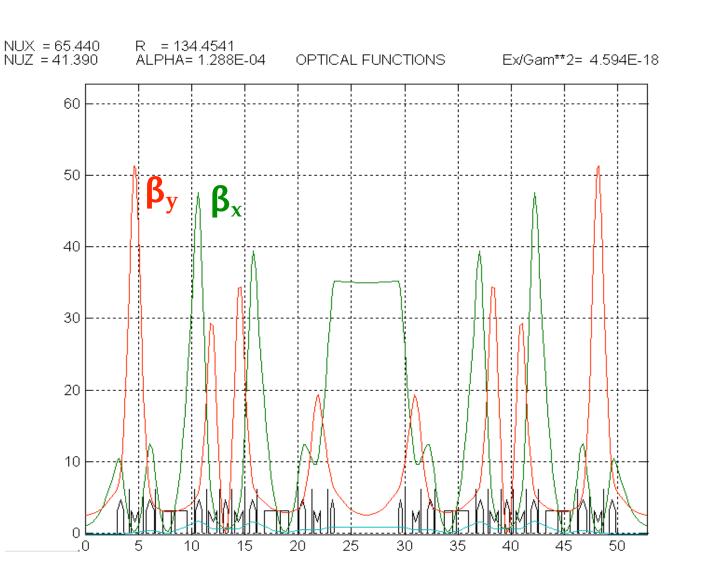




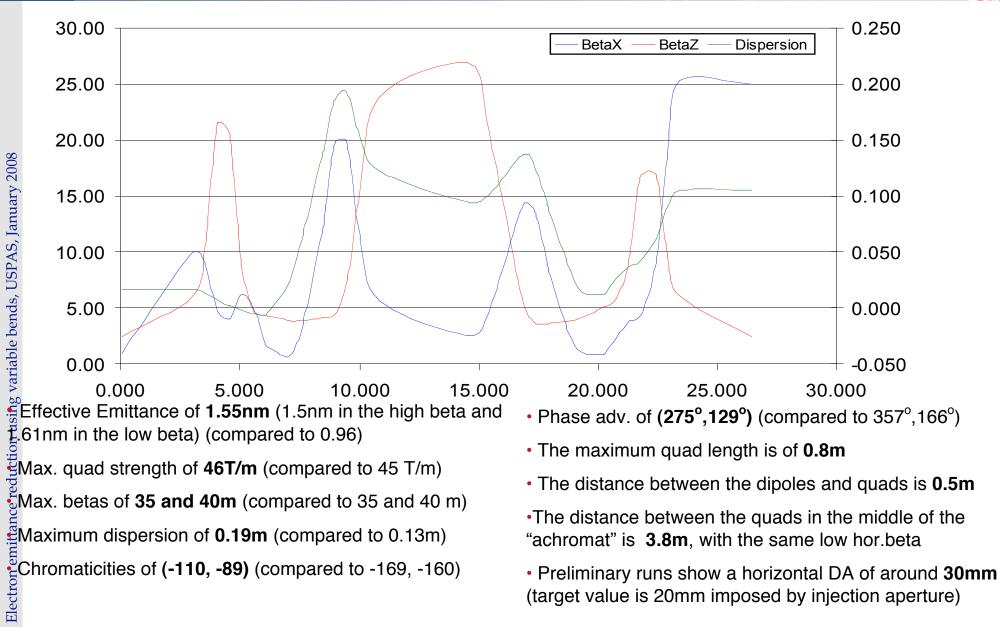
Some comments...

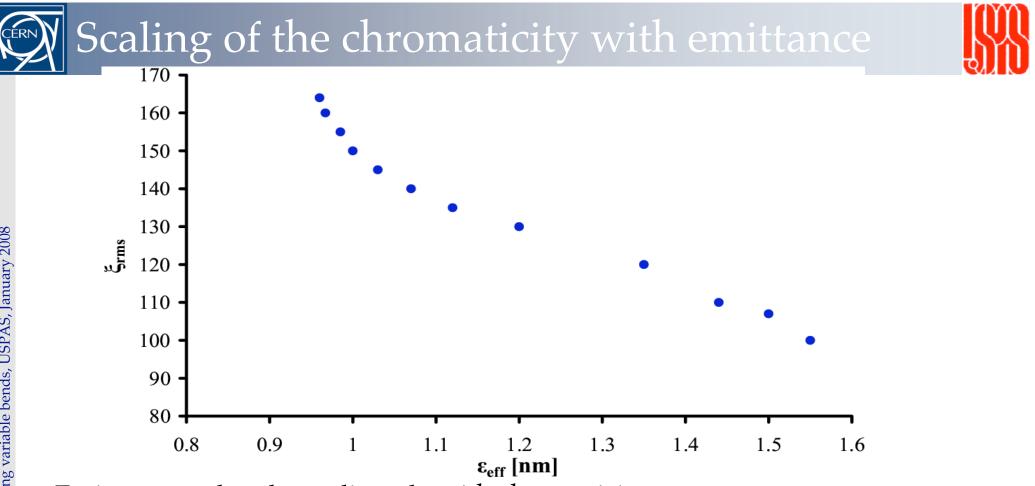


- The maximum quad length is of **0.9m**
- The distance between the dipoles and quads is **0.5m** (min. distance allowed between dipoles and quads)
- The distance between the quads in the middle of the "achromat" is bigger than **3m**
- In that area, the hor. beta is small (only efficient for vertical chromaticity correction)
- This space can be occupied by another dipole or ID element (convergence between TBA and DVB solution)
- Preliminary non-linear optimisation showed poor DA



Relaxed DVB with low energy spread





- Emittance scales almost linearly with chromaticity.
- Question to be answered: lowest emittance that can be achieved which leading to a reasonable DA.

Preliminary scaling suggests that this emittance may be found around 1.3nm
Top-up could allow a small of momentum DA (lifetime), at least 10mm are

mandatory for ensuring efficient injection.





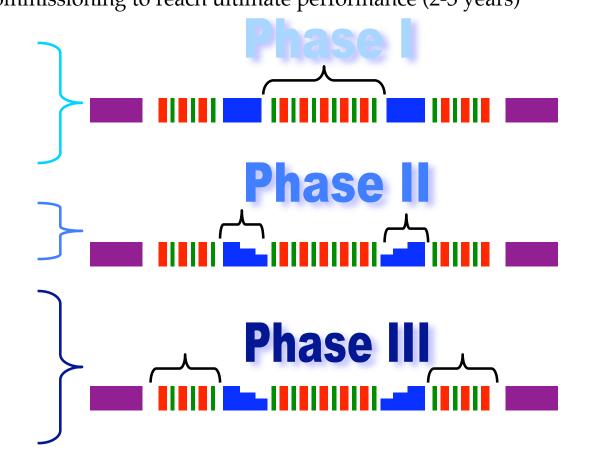
Ultimate lattice drawbacks

Long interruption time for installation of all componentsLong commissioning to reach ultimate performance (2-3 years)

Changing half of each cell (achromat) Increase the phase advance to reach **2nm** Increase the current to **300mA** (feed-back) **3-fold increase** of brilliance

All dipoles replaced by variable bends Small gain in emittance

All straight section magnets are replaced **Sub-nanometer** emittance An RF upgrade to reach more than **500mA** Brilliance increased by a **factor of 10**





- Adequate **dynamic aperture** for high phase advance cells
- Variable bending magnets field quality
- Building high gradient quadrupoles with incorporated sextupole components
- Design of new **absorbers** to sustain high beam power due to current upgrade
- High-gradient magnets need low gaps and small vacuum chambers, i.e. impedance increase (NEG coating)
- Design of **septum** with smaller sheet thickness
- Optimising injection process (booster, transfer lines) to allow continuous **top-up operation**